

Product Change Notification



Product Group: Vishay Siliconix/ SIL-0022017 / January 30, 2017

SI7252DP Data Sheet Update

DESCRIPTION OF CHANGE: Vishay Siliconix announces an update to the Drain-Source Resistance (Rdson) values for part number SI7252DP-T1-GE3. The Rdson values will be relaxed by 1mOhm for Gate-Source voltages of 10V, 7.5V and 6.0V. Please see the table below for the updated ratings.

CLASSIFICATION OF CHANGE: Data sheet change

REASON FOR CHANGE: Relaxation of Rdson specifications to maximize Final Test Yields

EXPECTED INFLUENCE ON QUALITY/RELIABILTY: Updates to the Drain-Source resistance (Rdson) for 10Vgs, 7.5Vgs and 6.0Vgs will not cause any change to product quality or reliability.

Current (Old)Rdson (Ω) Rating	Proposed (New)Rdson (Ω) Rating
0.017 @ 10Vgs	0.018 @ 10Vgs
0.018 @ 7.5Vgs	0.019 @ 7.5Vgs
0.020 @ 6Vgs	0.021 @ 6Vgs

PRODUCT CATAGORY: POWER MOSFET

PART NUMBERS/SERIES/FAMILIES AFFECTED: SI7252DP-T1-GE3

VISHAY BRAND(s): Vishay Siliconix

SAMPLE AVAILABILITY: Available now

PRODUCT IDENTIFICATION: No Changes will be made to product identification

This PCN is considered approved, without further notification, unless we receive specific customer concerns before April 30, 2017 as specified by contract.

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